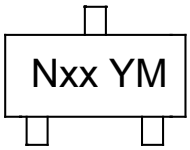
Marking Information



Nxx = Product Type Marking Code
(See Table in Features)
YM = Date Code Marking
Y or $\underline{Y}$ = Year (ex: I = 2021)
M or $\underline{M}$ = Month (ex: 9 = September)

Date Code Key

Year	2002	…	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	O	…	I	J	K	L	M	N	O	P	R	S

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	$I_{C(MAX)}$	100	mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	150	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{\theta JA}$	833	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50	—	—	V	I_C = 50µA
Collector-Emitter Breakdown Voltage	BV_{CEO}	50	—	—	V	I_C = 1mA
Emitter-Base Breakdown Voltage	BV_{EBO}	5	—	—	V	I_E = 50µA
Collector Cutoff Current	I_{CBO}	—	—	0.5	µA	V_{CB} = 50V
Emitter Cutoff Current	I_{EBO}	—	—	0.5	µA	V_{EB} = 4V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	0.3	V	I_C/I_B = 10mA/1mA DDTC113TE I_C/I_B = 5mA/0.5mA DDTC123TE I_C/I_B = 2.5mA/0.25mA DDTC143TE I_C/I_B = 1mA/0.1mA DDTC114TE I_C/I_B = 5mA/0.5mA DDTC124TE I_C/I_B = 2.5mA/0.25mA DDTC144TE I_C/I_B = 1mA/0.1mA DDTC115TE I_C/I_B = 0.5mA/0.05mA DDTC125TE
DC Current Transfer Ratio	h_{FE}	100	250	600	—	I_C = 1mA, V_{CE} = 5V
Input Resistor (R_1) Tolerance	ΔR_1	-30	—	+30	%	—
Gain-Bandwidth Product (Note 6)	f_T	—	250	—	MHz	V_{CE} = 10V, I_E = -5mA, f = 100MHz

Notes: 5. Mounted on FR-4 PC Board with minimum recommended pad layout.
6. Transistor only.

Typical Curves – DDTC114TE

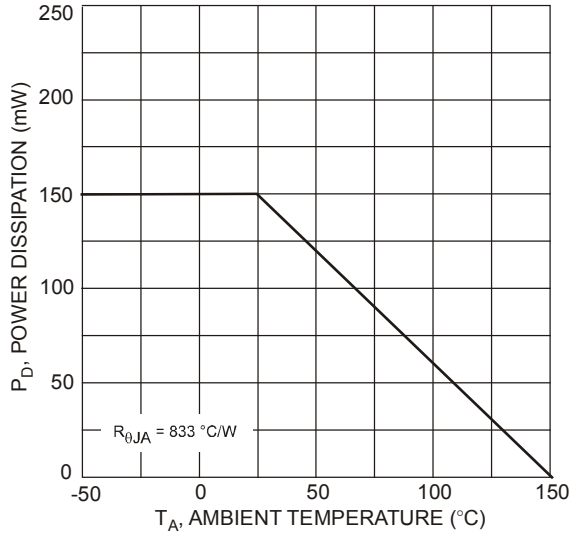


Fig. 1 Power Dissipation vs. Ambient Temperature

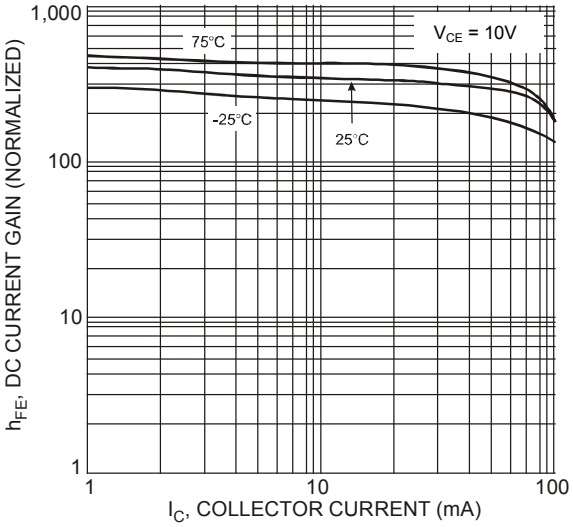


Fig. 2 Typical DC Current Gain vs. Collector Current

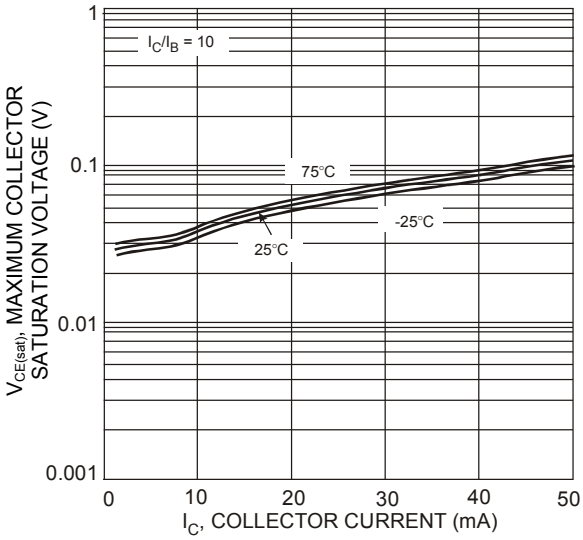


Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current

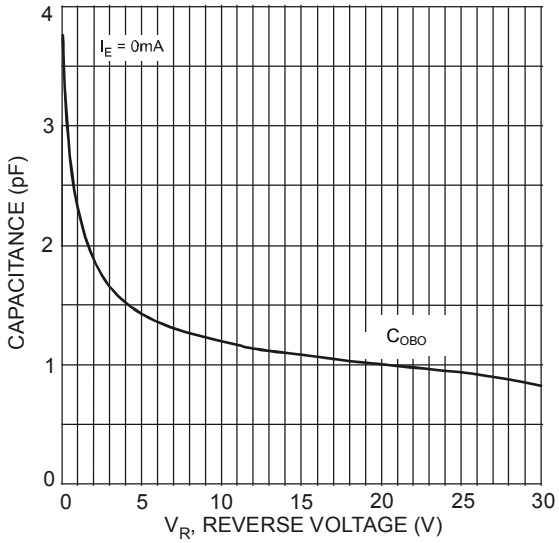


Fig. 4 Typical Capacitance Characteristics

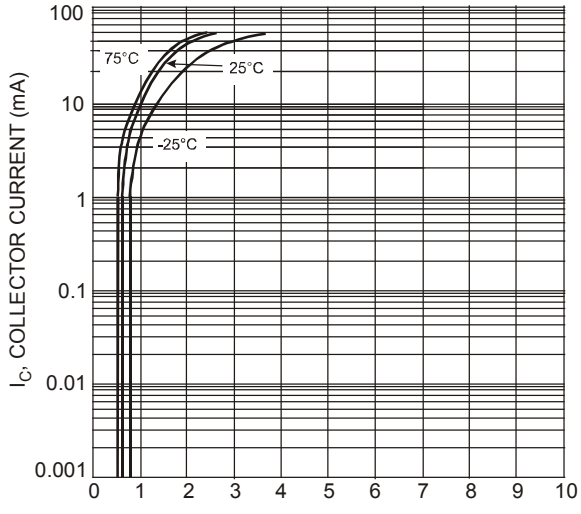


Fig. 5 Collector Current vs. Input Voltage

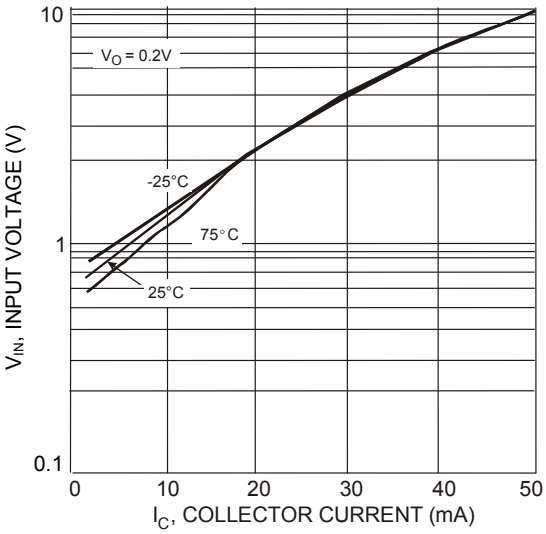
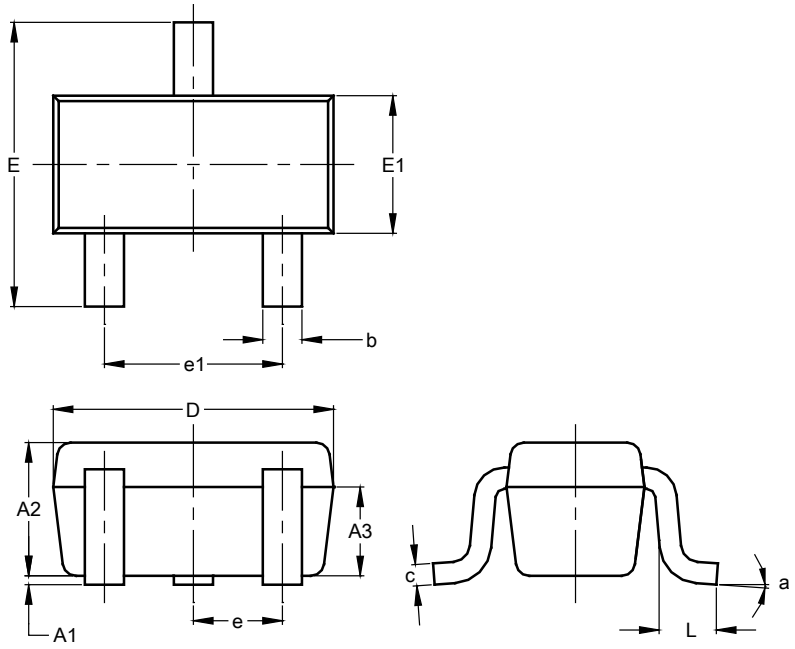


Fig. 6 Input Voltage vs. Collector Current

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

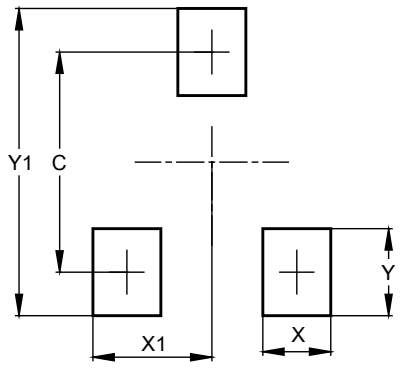


SOT523			
Dim	**Min**	**Max**	**Typ**
A1	0.00	0.10	0.05
A2	0.60	0.80	0.75
A3	0.45	0.65	0.50
b	0.15	0.30	0.22
c	0.10	0.20	0.12
D	1.50	1.70	1.60
E	1.45	1.75	1.60
E1	0.75	0.85	0.80
e	0.50 BSC		
e1	0.90	1.10	1.00
L	0.20	0.40	0.33
a	0°	--	8°
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)
C	1.29
X	0.40
X1	0.70
Y	0.51
Y1	1.80

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